


International IR Rectifier

SERIES IRK.166, .196, .236

STANDARD RECOVERY DIODES

NEW INT-A-pak Power Modules

Features

- High Voltage
- Electrically Isolated by DBC Ceramic (Al_2O_3)
- 3500 V_{RMS} Isolating Voltage
- Industrial Standard Package
- High Surge Capability
- Glass Passivated Chips
- Modules uses High Voltage Power diodes in four Basic Configurations
- Simple Mounting
- UL E78996 approved 

165 A
195 A
230 A

Applications

- DC Motor Control and Drives
- Battery Charges
- Welders
- Power Converters

Major Ratings and Characteristics

Parameters	IRK.166..	IRK.196..	IRK.236..	Units	
$I_{F(AV)}$	165	195	230	A	
@ T_C	100	100	100	°C	
$I_{F(RMS)}$	260	305	360	A	
I_{FSM}	@ 50Hz	4000	4750	5500	A
	@ 60Hz	4200	4980	5765	A
I_2t	@ 50Hz	80	113	151	KA ² s
	@ 60Hz	73	103	138	KA ² s
$I^2\sqrt{t}$	798	1130	1516	KA ² \sqrt{s}	
V_{RRM}	400 to 1600			V	
T_J range	-40 to 150			°C	

CASE STYLE NEW INT-A-PAK



Electrical Specifications

Voltage Ratings

Type number	Voltage Code	V_{RRM} , Maximum repetitive peak reverse voltage V	V_{RSM} , Maximum non-repetitive peak reverse voltage V	I_{RRM} 150°C mA
IRK.166	04	400	500	20
IRK.196	08	800	900	
IRK.236	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

Forward Conduction

Parameter	IRK.166	IRK.196	IRK.236	Units	Conditions
$I_{F(AV)}$ Max. average on-state current @ Case temperature	165	195	230	A	180° conduction, half sine wave
	100	100	100	°C	
$I_{F(RMS)}$ Max. RMS on-state current	260	305	360	A	
I_{FSM} Maximum peak, one-cycle on-state, non-repetitive surge current	4000	4750	5500	A	t = 10ms No voltage
	4200	4980	5765		t = 8.3ms reapplied
	3350	4000	4630		t = 10ms 100% V_{RRM}
	3500	4200	4850		t = 8.3ms reapplied
I^2t Maximum I^2t for fusing	80	113	151	KA ² s	t = 10ms No voltage
	73	103	138		t = 8.3ms reapplied
	56	80	107		t = 10ms 100% V_{RRM}
	52	73	98		t = 8.3ms reapplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	798	1130	1516	KA ² √s	t = 0.1 to 10ms, no voltage reapplied
$V_{F(TO)1}$ Low level value of threshold voltage	0.73	0.69	0.7	V	($16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), @ T_J max.
$V_{F(TO)2}$ High level value of threshold voltage	0.88	0.78	0.83	V	($I > \pi \times I_{F(AV)}$), @ T_J max.
r_{t1} Low level value on-state slope resistance	1.5	1.3	1.2	mΩ	($16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), @ T_J max.
r_{t2} High level value on-state slope resistance	1.26	1.2	1.07	mΩ	($I > \pi \times I_{F(AV)}$), @ T_J max.
V_{FM} Maximum forward voltage drop	1.43	1.38	1.46	V	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = 25^\circ\text{C}$, 180° conduction Av. power = $V_{F(TO)} \times I_{F(AV)} + r_f \times (I_{F(RMS)})^2$

Blocking

I_{RRM} Maximum peak reverse and off-state leakage current	20	mA	$T_J = 150^\circ\text{C}$
V_{INS} RMS isolation voltage	3500	V	50Hz, circuit to base, all terminals shorted, t = 1s

Thermal and Mechanical Specifications

Parameter	IRK.166	IRK.196	IRK.236	Units	Conditions
T _J Max. junction operating temperature range	-40 to 150			°C	
T _{stg} Max. storage temperature range	-40 to 150			°C	
R _{thJC} Max. thermal resistance, junction to case	0.2	0.16	0.14	K/W	DC operation, per junction
R _{thCS} Max. thermal resistance, case to heatsink	0.05			K/W	Mounting surface smooth, flat and greased Per module
T Mounting torque ± 10%	IAP to heatsink busbar to IAP			Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.
	4 to 6				
wt Approximate weight	200 (7.1)			g (oz)	
Case Style	New Int-A-Pak				

ΔR Conduction (per Junction)

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Devices	Sinusoidal conduction @ T _J max.					Rectangular conduction @ T _J max.					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRK.166	0.025	0.03	0.038	0.055	0.089	0.018	0.031	0.041	0.057	0.089	K/W
IRK.196	0.016	0.019	0.024	0.034	0.053	0.012	0.02	0.026	0.035	0.054	
IRK.236	0.009	0.010	0.014	0.018	0.025	0.008	0.012	0.015	0.019	0.025	

Ordering Information Table

Device Code

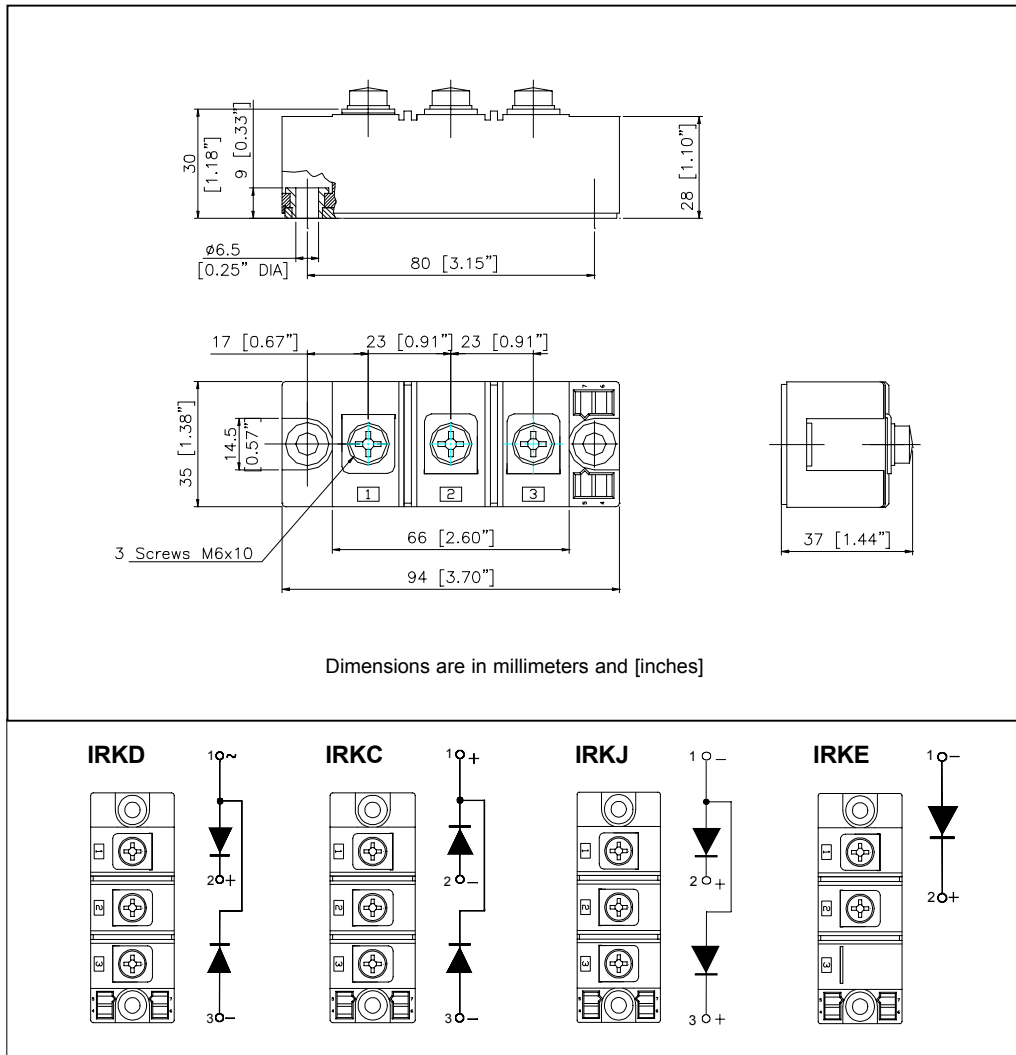
IRK	D	236	/	16
①	②	③		④

- 1** - Module Type
- 2** - Circuit Configuration
- 3** - Current Rating: I_{F(AV)}
- 4** - Voltage Code: Code x 100 = V_{RRM}

IRK.166, .196, .236 Series

Bulletin I27116 rev. C 03/02

Outline Table



NOTE: To order the Optional Hardware see Bulletin I27900

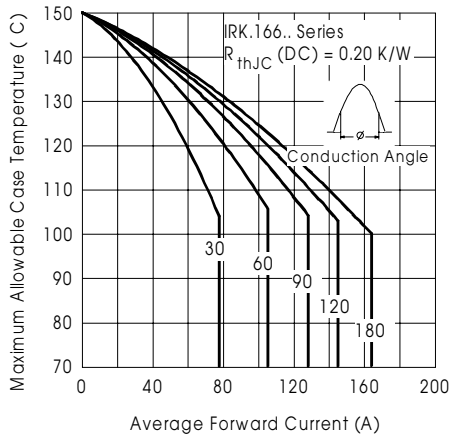


Fig. 1 - Current Ratings Characteristics

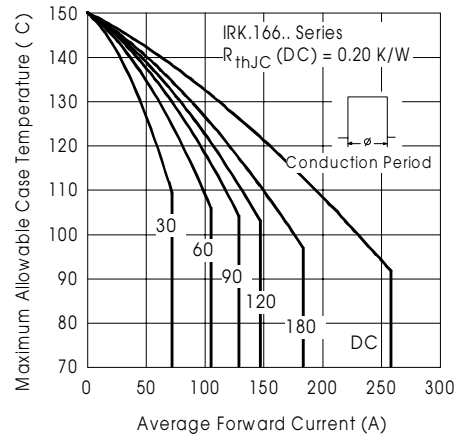


Fig. 2 - Current Ratings Characteristics

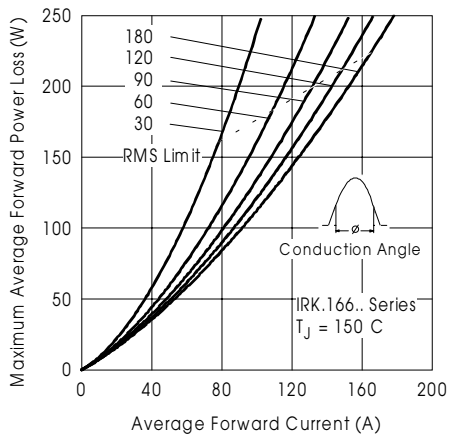


Fig. 3 - On-State Power Loss Characteristics

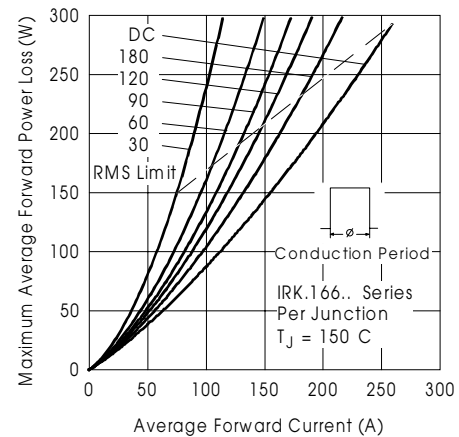


Fig. 4 - On-State Power Loss Characteristics

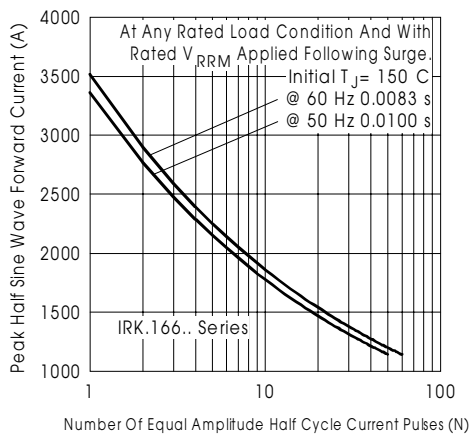


Fig. 5 - Maximum Non-Repetitive Surge Current

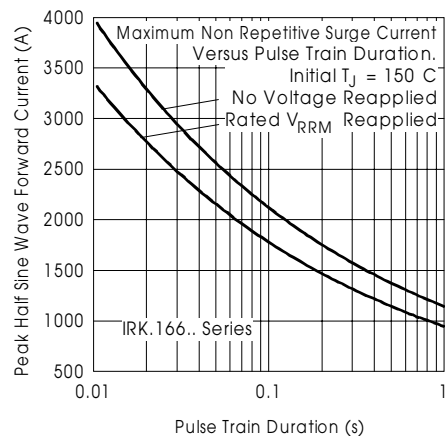


Fig. 6 - Maximum Non-Repetitive Surge Current

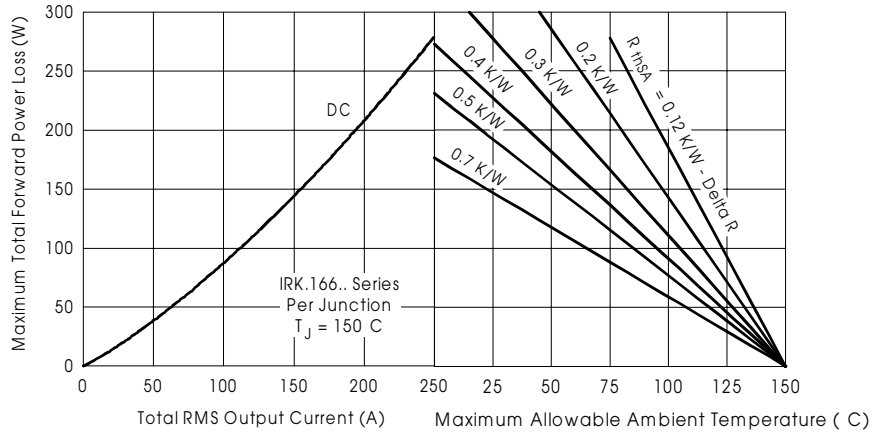


Fig.7 - On State Power Loss Characteristics

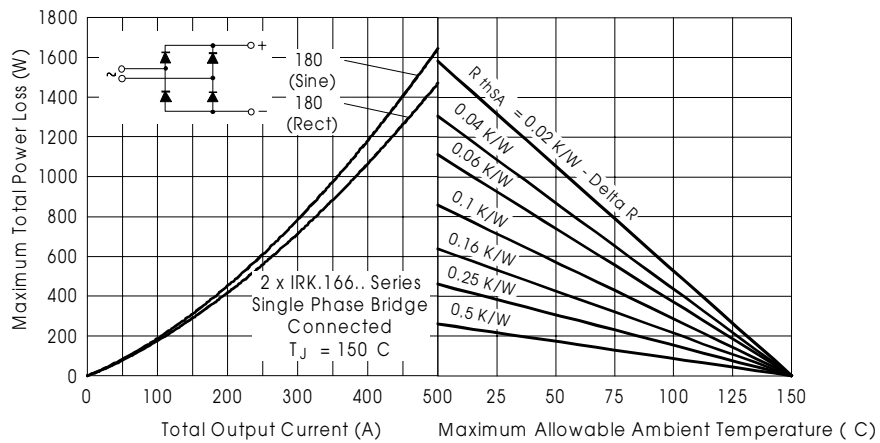


Fig.8 - On State Power Loss Characteristics

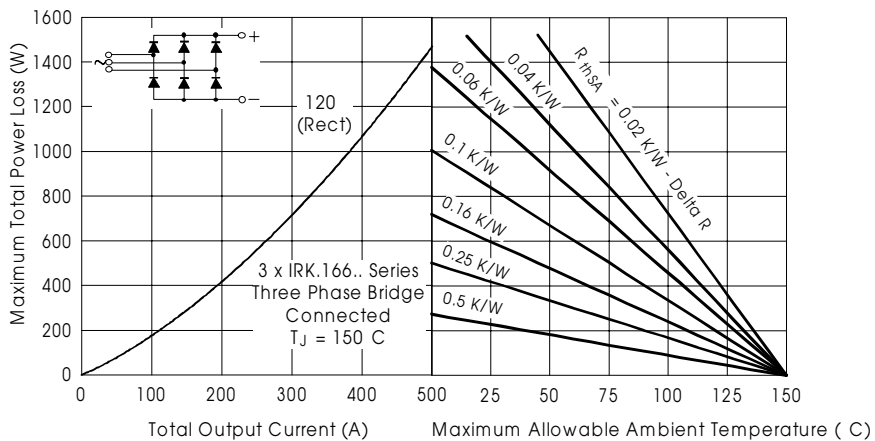


Fig.9 - On State Power Loss Characteristics

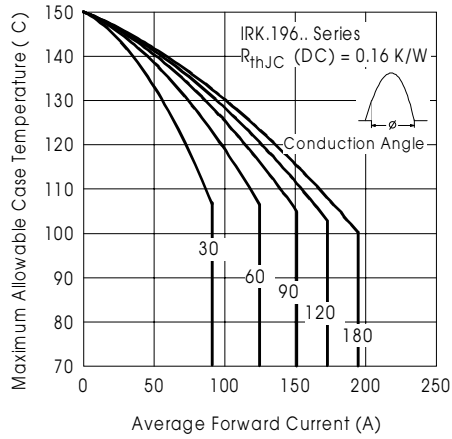


Fig. 10 - Current Ratings Characteristics

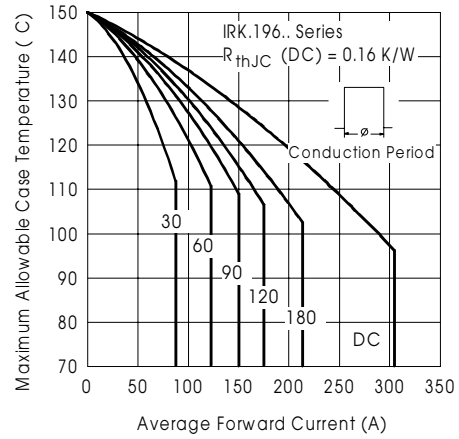


Fig. 11 - Current Ratings Characteristics

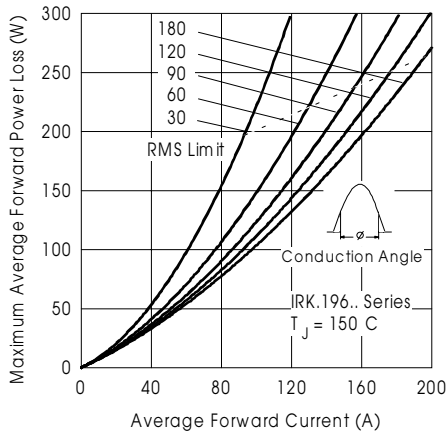


Fig. 12 - On-State Power Loss Characteristics

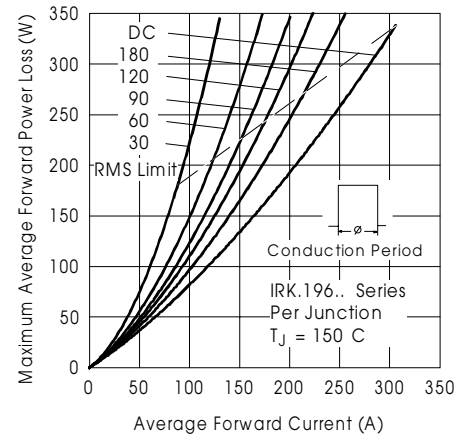


Fig. 13 - On-State Power Loss Characteristics

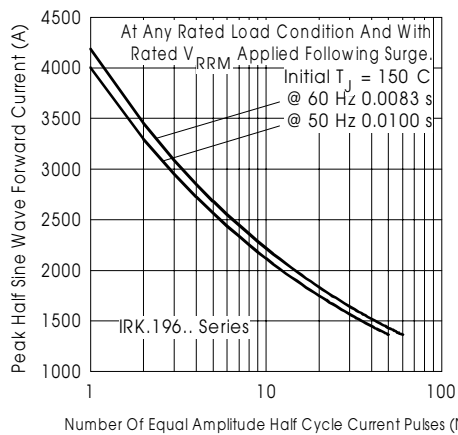


Fig. 14 - Maximum Non-Repetitive Surge Current

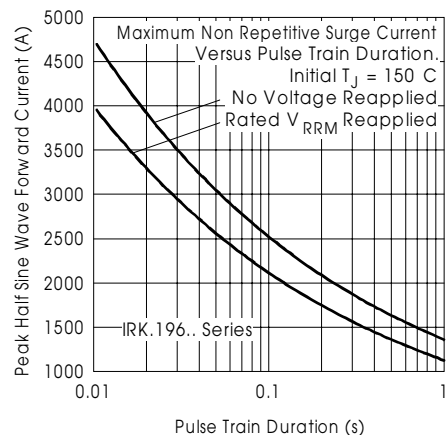


Fig. 15 - Maximum Non-Repetitive Surge Current

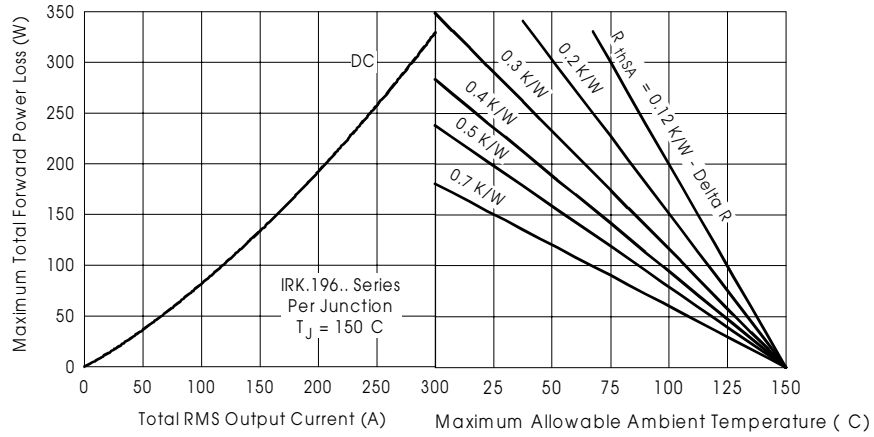


Fig.16 - On State Power Loss Characteristics

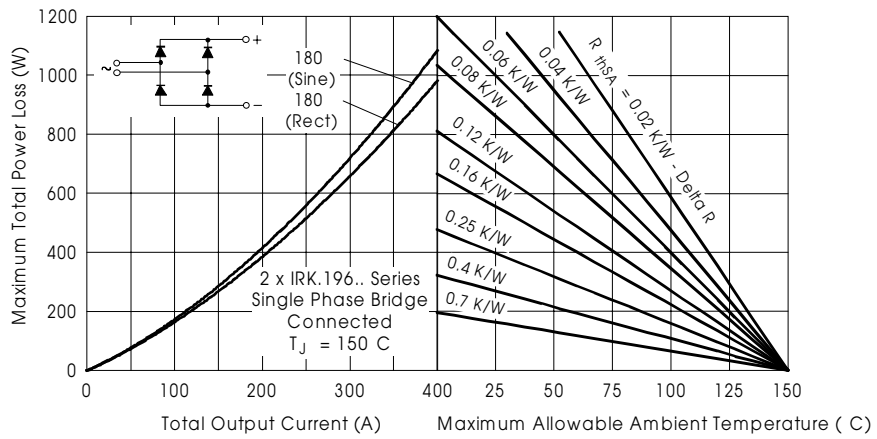


Fig.17 - On State Power Loss Characteristics

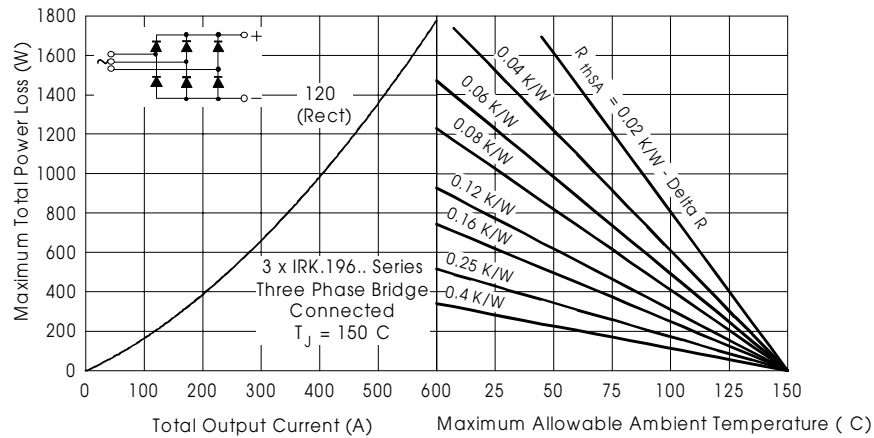


Fig.18- On State Power Loss Characteristics

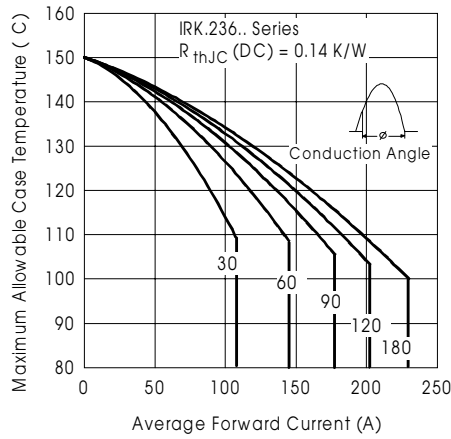


Fig. 19 - Current Ratings Characteristics

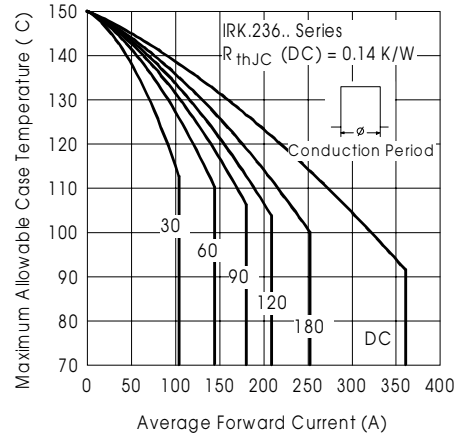


Fig. 20 - Current Ratings Characteristics

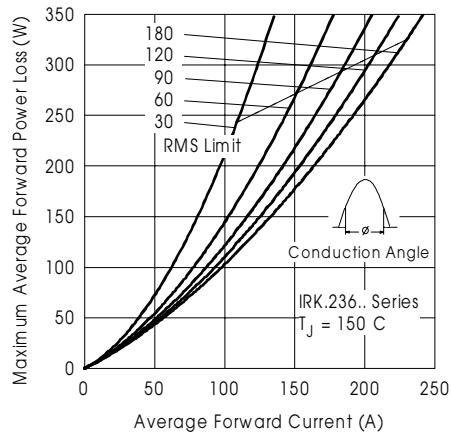


Fig. 21 - On-State Power Loss Characteristics

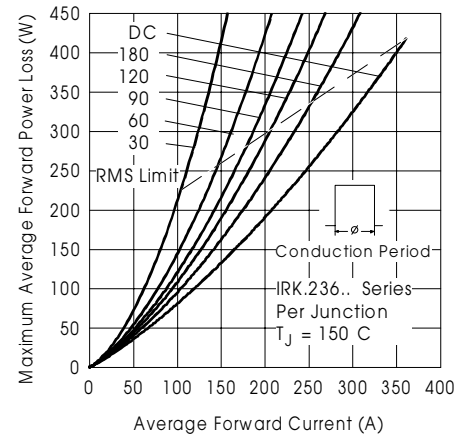


Fig. 22 - On-State Power Loss Characteristics

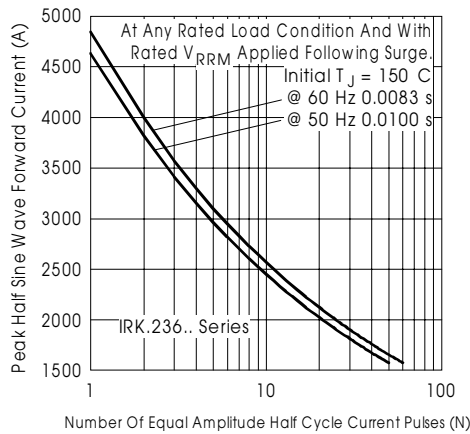


Fig. 23 - Maximum Non-Repetitive Surge Current

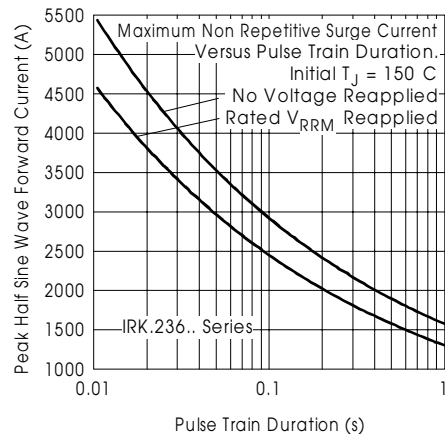


Fig. 24 - Maximum Non-Repetitive Surge Current

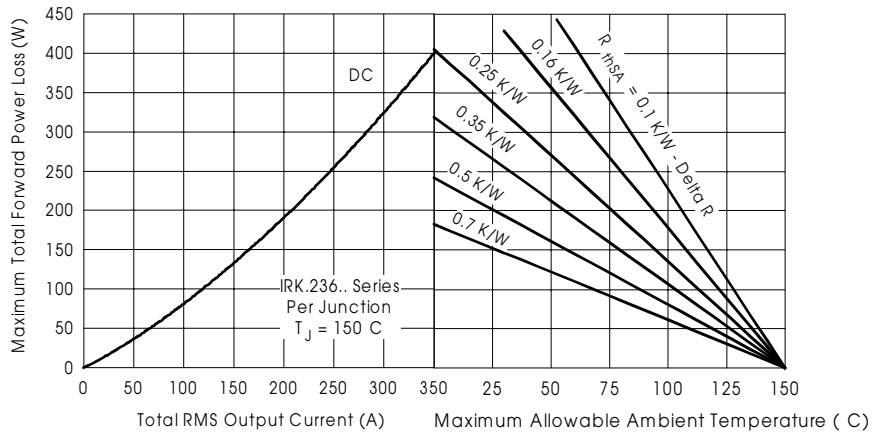


Fig.25 - On State Power Loss Characteristics

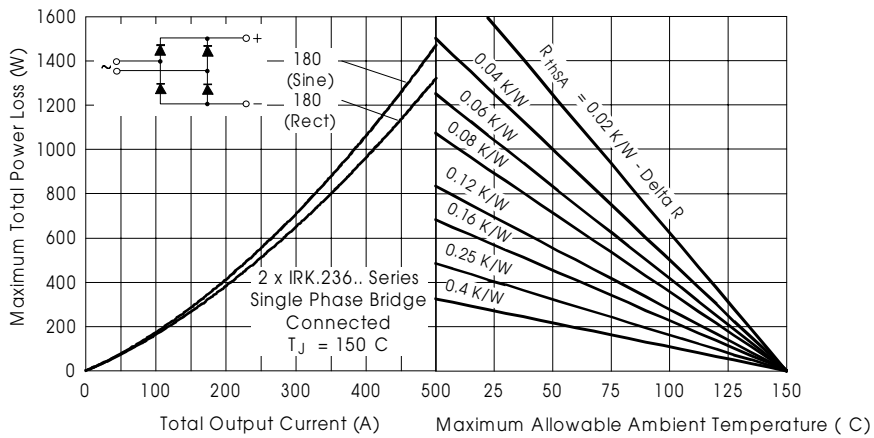


Fig.26 - On State Power Loss Characteristics

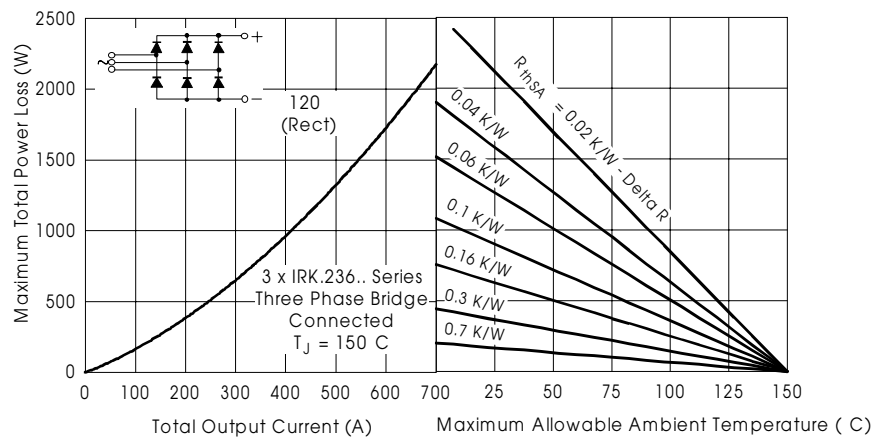


Fig.27 - On State Power Loss Characteristics

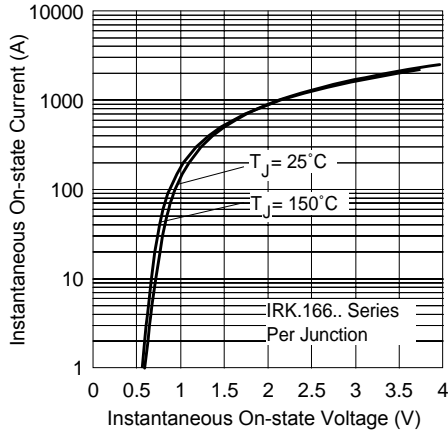


Fig.28 - On State Voltage Drop Characteristics

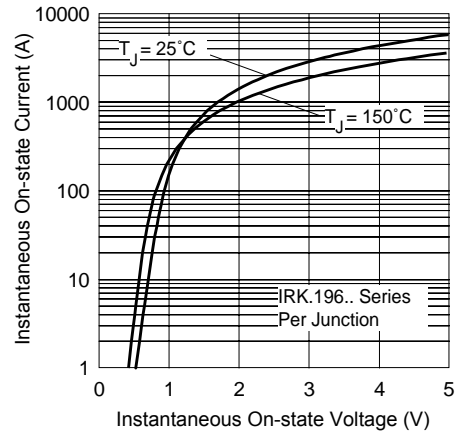


Fig.29 - On State Voltage Drop Characteristics

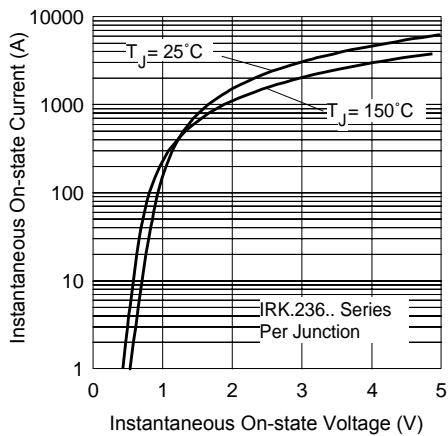


Fig.30 - On State Voltage Drop Characteristics

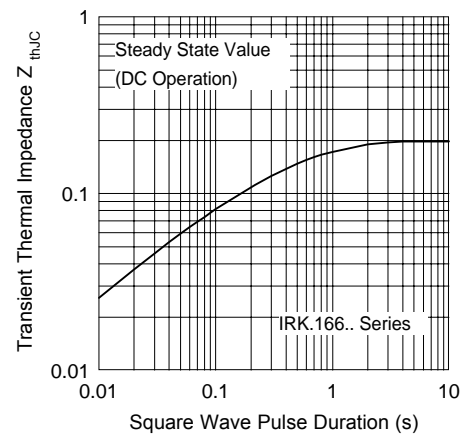


Fig.31 - Thermal Impedance Z_{thJC} Characteristics

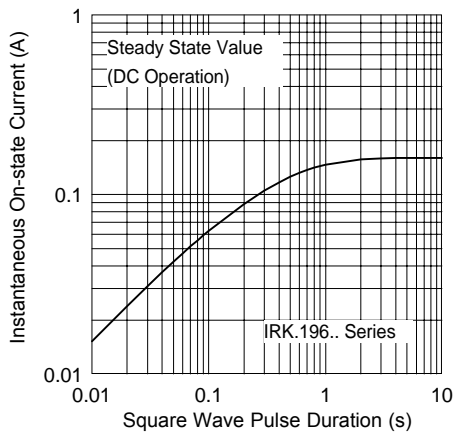


Fig.32 - Thermal Impedance Z_{thJC} Characteristics

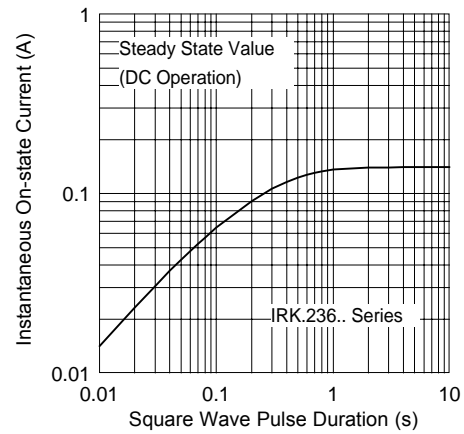


Fig.33 - Thermal Impedance Z_{thJC} Characteristics

IRK.166, .196, .236 Series

Bulletin I27116 rev. C 03/02

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Data and specifications subject to change without notice.
This product has been designed and qualified for Multiple Level.
Qualification Standards can be found on IR's Web site.

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